

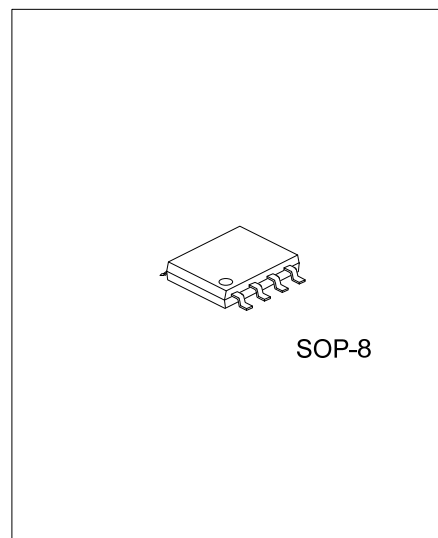
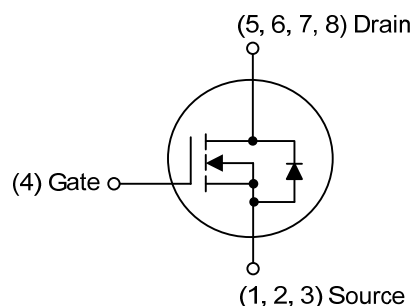
**UT4410****Power MOSFET****N-CHANNEL 30-V (D-S) MOSFET****DESCRIPTION**

The UTC **UT4410** is a N-channel MOSFET, it uses UTC's advanced technology to provide the customers with a minimum on state resistance and high switching speed.

The UTC **UT4410** is suitable for load switch and battery protection applications.

FEATURES

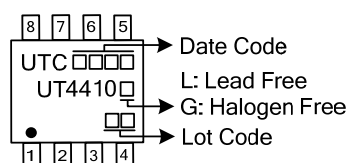
- * $R_{DS(ON)} \leq 11 \text{ m}\Omega$ @ $V_{GS}=10\text{V}$, $I_D=8.0\text{A}$
- * $R_{DS(ON)} \leq 15 \text{ m}\Omega$ @ $V_{GS}=4.5\text{V}$, $I_D=8.0\text{A}$
- * Fast switching capability
- * Avalanche energy specified
- * Improved dv/dt capability, high ruggedness

SYMBOL**ORDERING INFORMATION**

Ordering Number		Package	Pin Assignment								Packing
Lead Free	Halogen Free		1	2	3	4	5	6	7	8	
UT4410L-S08-R	UT4410G-S08-R	SOP-8	S	S	S	G	D	D	D	D	Tape Reel

Note: Pin Assignment: G: Gate D: Drain S: Source

UT4410G-S08-R (1) Packing Type (2) Package Type (3) Green Package	(1) R: Tape Reel (2) S08: SOP-8 (3) G: Halogen Free and Lead Free, L: Lead Free
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MARKING

■ ABSOLUTE MAXIMUM RATINGS (T_C=25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Drain-Source Voltage	V _{DSS}	30	V
Gate-Source Voltage	V _{GSS}	±20	V
Continuous Drain Current	I _D	11	A
Pulsed Drain Current	I _{DM}	50	A
Avalanche Energy	E _{AS}	4	mJ
Power Dissipation	P _D	1.8	W
Junction Temperature	T _J	-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating: Pulse width limited by maximum junction temperature.

3. L = 0.1mH, I_{AS} = 9.0A, V_{DD} = 20V, R_G = 25Ω, Starting T_J = 25°C

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient	θ _{JA}	90	°C/W
Junction to Case	θ _{JC}	69 (Note)	°C/W

Note: Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

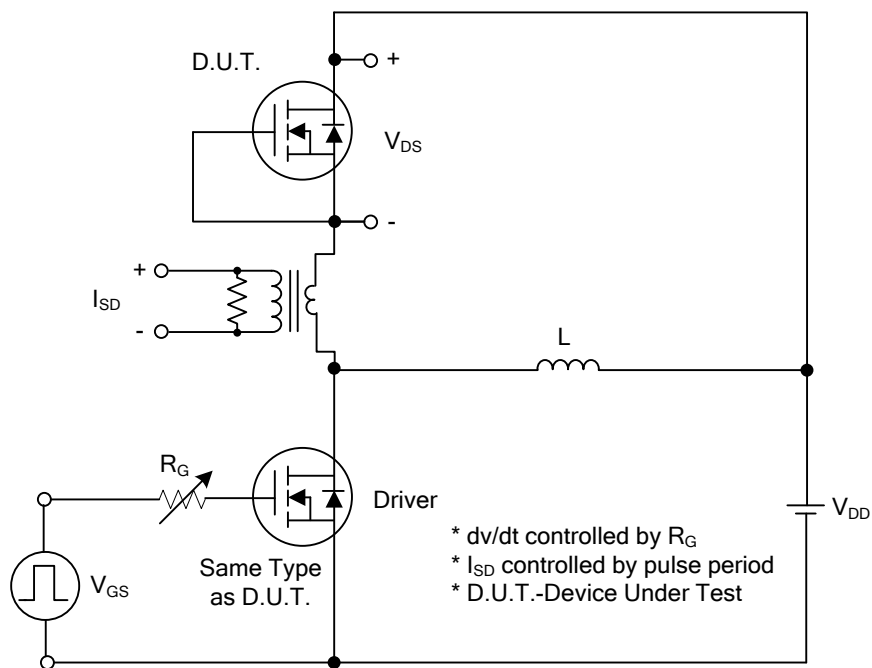
■ ELECTRICAL CHARACTERISTICS (T_A =25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV _{DSS}	I _D =-250μA, V _{GS} =0V	30			V
Drain-Source Leakage Current	I _{DSS}	V _{DS} =30V, V _{GS} =0V			1	μA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V			±100	nA
ON CHARACTERISTICS						
Gate-Threshold Voltage	V _{GS(TH)}	V _{DS} =V _{GS} , I _D =250μA	1.0		3.0	V
Static Drain–Source On–Resistance(Note)	R _{DS(ON)}	V _{GS} =10V, I _D =8.0A			11	mΩ
		V _{GS} =4.5V, I _D =8.0A			15	
DYNAMIC PARAMETERS						
Input Capacitance	C _{ISS}	V _{DS} =15V, V _{GS} =0V, f=1.0MHz		820		pF
Output Capacitance	C _{OSS}			280		pF
Reverse Transfer Capacitance	C _{RSS}			150		pF
SWITCHING PARAMETERS						
Total Gate Charge	Q _G	V _{DS} =15V, V _{GS} =10V, I _D =11A		38		nC
Gate Source Charge	Q _{GS}			5		nC
Gate Drain Charge	Q _{GD}			11		nC
Turn-ON Delay Time	t _{D(ON)}	V _{DS} =15V, V _{GS} =4.5V, I _D =11A, R _G =3.0Ω (Note 1, 2)		8		ns
Turn-ON Rise Time	t _R			16		ns
Turn-OFF Delay Time	t _{D(OFF)}			23		ns
Turn-OFF Fall-Time	t _F			21		ns
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS						
Maximum Body-Diode Continuous Current	I _S				11	A
Maximum Body-Diode Pulsed Current	I _{SM}				50	A
Diode Forward Voltage	V _{SD}	I _S =11A , V _{GS} =0V			1.4	V
Reverse Recovery Time (Note 1)	t _{rr}	I _S =11A, V _{GS} =0V		210		ns
Reverse Recovery Charge	Q _{rr}	dl _F /dt=100A/μs (Note1)		1		μC

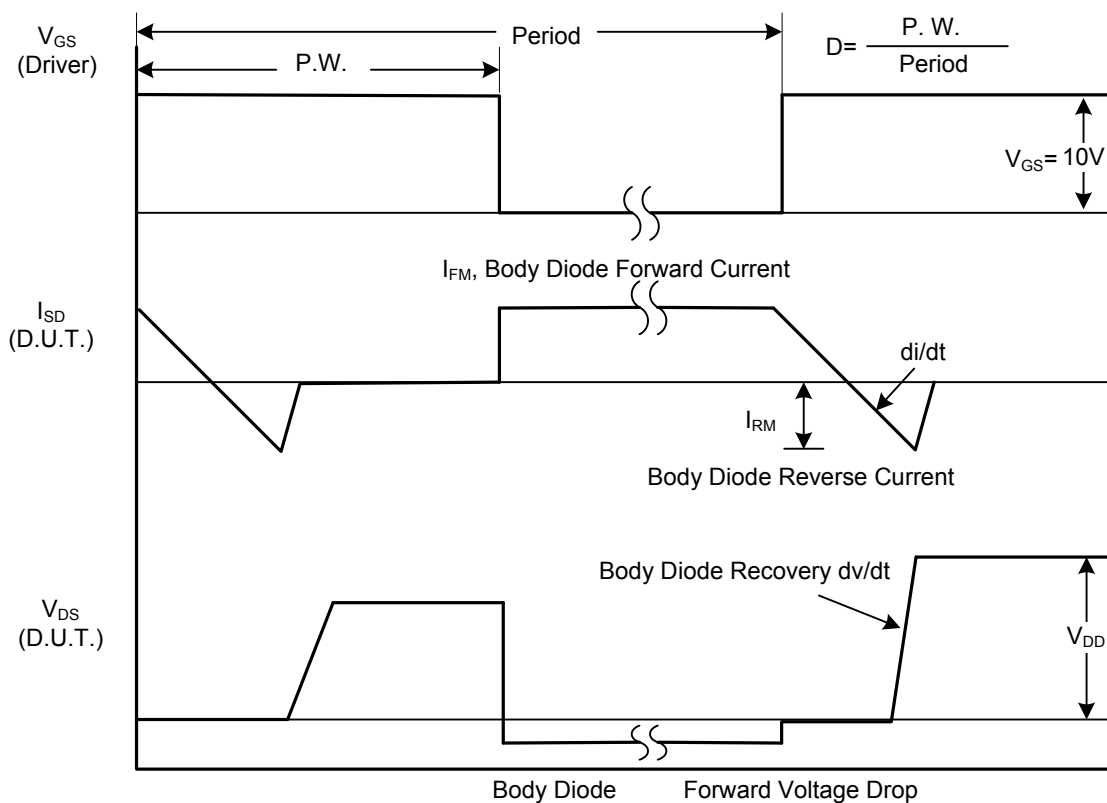
Notes: 1. Pulse Test : Pulse width ≤ 300μs, Duty cycle ≤ 2%.

2. Essentially independent of operating temperature.

■ TEST CIRCUITS AND WAVEFORMS

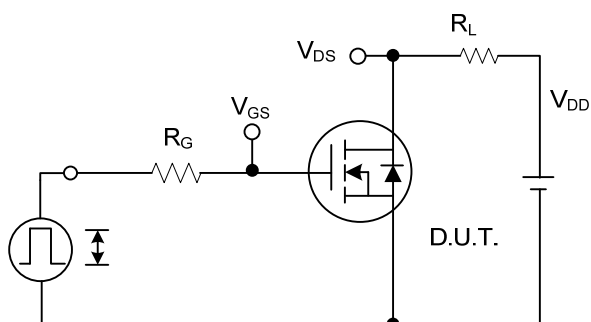


Peak Diode Recovery dv/dt Test Circuit

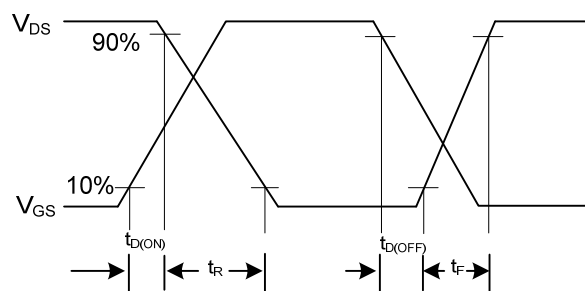


Peak Diode Recovery dv/dt Waveforms

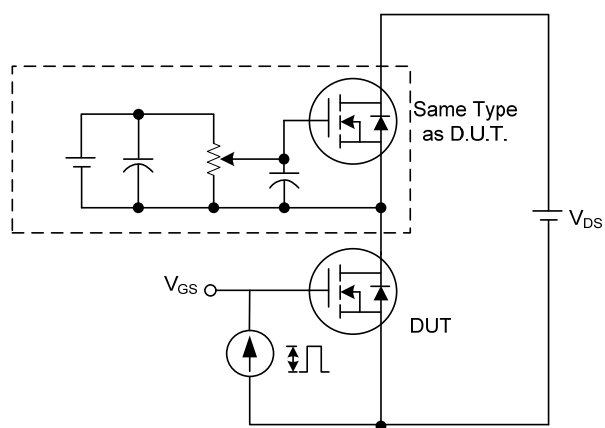
■ TEST CIRCUITS AND WAVEFORMS



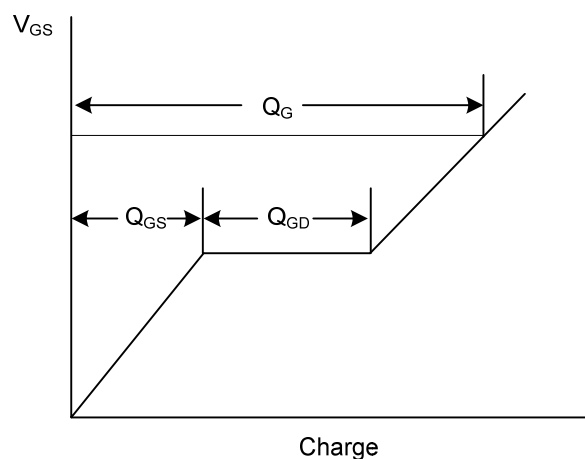
Switching Test Circuit



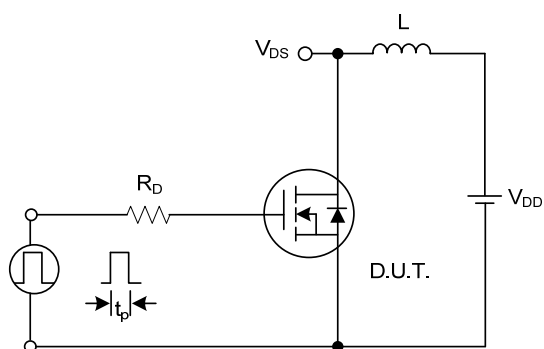
Switching Waveforms



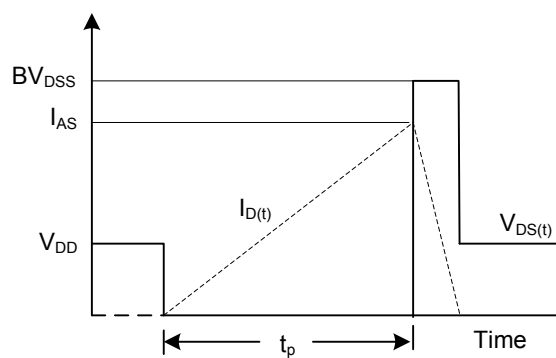
Gate Charge Test Circuit



Gate Charge Waveform



Unclamped Inductive Switching Test Circuit



Unclamped Inductive Switching Waveforms

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